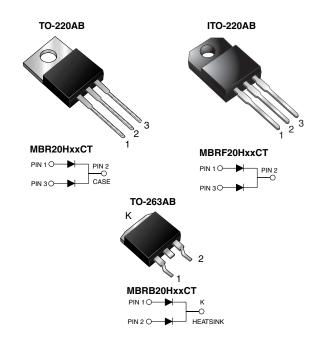


## MBR20HxxCT, MBRF20HxxCT, MBRB20HxxCT

Vishay General Semiconductor

## **Dual Common Cathode Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 10 A					
V <sub>RRM</sub>	35 V to 60 V					
I <sub>FSM</sub>	I <sub>FSM</sub> 150 A					
V <sub>F</sub>	0.55 V, 0.61 V					
I <sub>R</sub>	100 µA					
T <sub>J</sub> max.	175 °C					
Package	TO-220AB, ITO-220AB, TO-263AB					
Diode variations	Common cathode					

### FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum



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<b>MAXIMUM RATINGS</b> ( $T_c = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	MBR20H35CT	MBR20H45CT	MBR20H50CT	MBR20H60CT	UNIT		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	35	45	50 60				
Working peak reverse voltage	V <sub>RWM</sub>	35	45	50	60	V		
Maximum DC blocking voltage	V <sub>DC</sub>	35	45	50 60				
Maximum average forward rectified total device		20						
current (fig. 1) per diode	I <sub>F(AV)</sub>	10						
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS}$ = 4 A, L = 10 mH	E <sub>AS</sub>	80				mJ		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	150						
Peak repetitive reverse surge current per diode at $t_{\text{p}}$ = 2.0 $\mu\text{s},$ 1 kHz	I <sub>RRM</sub>	1.0 0.5				A		
Peak non-repetitive reverse energy (8/20 μs waveform)	E <sub>RSM</sub>	20 10				mJ		
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = 1.5 k $\Omega$	V <sub>C</sub>	25						
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000						
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to 175				°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500			V			

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBR20H35CT MBR20H45CT		MBR20H50CT MBR20H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	$I_{F} = 10 \text{ A}$	T <sub>C</sub> = 25 °C	-	0.63	-	0.71	
		I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C	0.49	0.55	0.57	0.61	v
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C	-	0.75	-	0.85	v
				$I_{F} = 20 \text{ A}$	T <sub>C</sub> = 125 °C	0.62	0.68	0.68
Maximum reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	(2) Rated V <sub>B</sub>	T <sub>J</sub> = 25 °C	-	100	-	100	μA
			T <sub>J</sub> = 125 °C	4.0	12	2.0	12	mA

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: Pulse width  $\leq 40\mbox{ ms}$ 

<b>THERMAL CHARACTERISTICS</b> ( $T_c = 25 \text{ °C}$ unless otherwise noted)						
ARAMETER SYMBOL MBR MBRF MBRB UNIT						
Typical resistance, junction to case per diode	$R_{\theta JC}$	2.0	4.0	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20H45CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF20H45CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB20H45CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB20H45CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR20H45CTHE3/45 <sup>(1)</sup>	1.85	45	50/tube	Tube		
ITO-220AB	MBRF20H45CTHE3/45 <sup>(1)</sup>	1.99	45	50/tube	Tube		
TO-263AB	MBRB20H45CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB20H45CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

#### Note

(1) AEC-Q101 qualified

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### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

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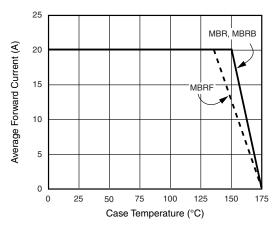


Fig. 1 - Forward Current Derating Curve (Total)

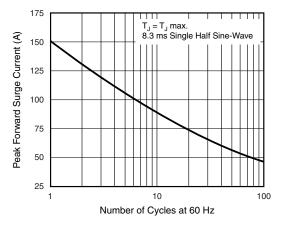
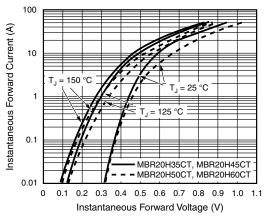
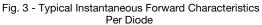


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode





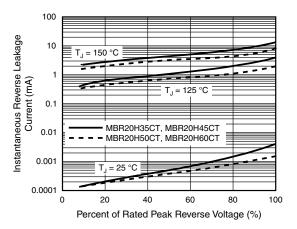


Fig. 4 - Typical Reverse Characteristics Per Diode

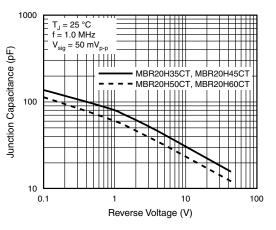
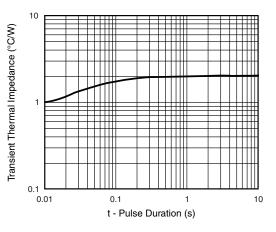


Fig. 5 - Typical Junction Capacitance Per Diode





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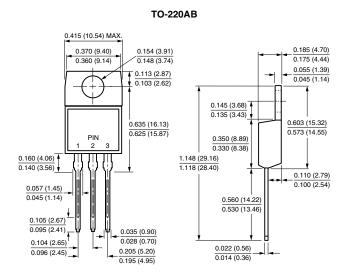
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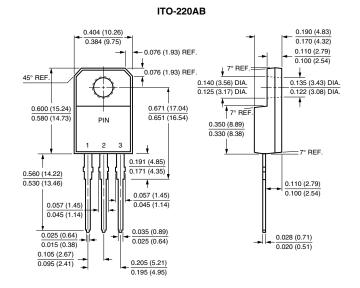


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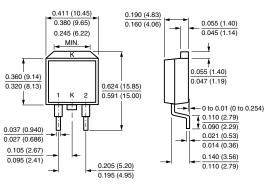
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

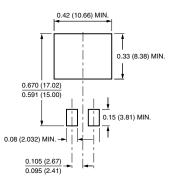




TO-263AB



Mounting Pad Layout





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